Heat Load on a Pillbox Cavity

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Abstract

Derivation of the power distribution from RF fields on the inner surfaces of a pillbox cavity made of multiple materials.

Introduction

Consider a cylindrical pillbox cavity with radius a and length L. The electromagnetic field amplitudes in SI units are given in cylindrical coordinates (r, ϕ, z) by

$$\vec{E}(r) = E_0 J_0(j_{01} \frac{r}{a}) \hat{\mathbf{z}}$$
$$\vec{B}(r) = \frac{E_0}{c} J_1(j_{01} \frac{r}{a}) \hat{\boldsymbol{\phi}}$$

in terms of Bessel functions of the first kind J_0 , J_1 with

$$\omega = c \frac{j_{01}}{a} = 2\pi f$$
$$J_0(j_{01}) = 0$$

where

- E_0 is the peak on-axis gradient
- $c \simeq 2.9979 \times 10^8$ m/s is the speed of light,
- f is the resonant frequency of the cavity and
- $j_{01} \simeq 2.4048$ is the smallest root of J_0

Stored energy

The electromagnetic energy density in the cavity volume is

$$w = \frac{1}{2} \left[\epsilon_0 E(r,t)^2 + \frac{1}{\mu_0} B(r,t)^2 \right]$$

and with the full time-dependent fields expressed as

$$\vec{E}(r,t) = \vec{E}(r) \cos \omega t$$

 $\vec{B}(r,t) = \vec{B}(r) \sin \omega t$

the total stored energy can be found when $\omega t = 0$ or π through

$$U = \epsilon_0 L \int_0^a dr \ 2\pi r \ E^2(r) = \frac{L}{\mu_0} \int_0^a dr \ 2\pi r \ B^2(r)$$

using

$$\int_0^1 dx \ x \ J_0^2(j_{01} \ x) = \int_0^1 dx \ x \ J_1^2(j_{01} \ x) = \frac{1}{2} \ J_1^2(j_{01})$$

as

$$U = J_1^2(j_{01}) \ (\pi \ a^2 \ L) \left[\frac{1}{2 \ \mu_0} \ \left(\frac{E_0}{c} \right)^2 \right]$$

where $J_1^2(j_{01}) \simeq 0.26951$ showing that the (spatial) average energy density is about 27% of the peak in this simple structure and does not depend on the aspect ratio.

Surface currents and power dissipation

In a cavity made of material with finite conductivity, power dissipation is due to a thin layer of current under the surface confined to the skin depth δ . The current density \vec{J} is given by

$$\vec{J}_{cr} = \frac{B_{\phi}(a)}{\mu_0 \,\delta_{cr}} \,\hat{\mathbf{z}}, \quad -\frac{L}{2} < z < \frac{L}{2}
\vec{J}_{e1} = \frac{B_{\phi}(r)}{\mu_0 \,\delta_{e1}} \,\hat{\mathbf{r}}, \quad z = -\frac{L}{2}
\vec{J}_{e2} = \frac{B_{\phi}(r)}{\mu_0 \,\delta_{e2}} \,\hat{\mathbf{r}}, \quad z = \frac{L}{2}$$

where

- $\mu_0 = 4\pi \times 10^{-7}$ H/m is the permeability of vacuum and
- the subscripts cr, e1 and e2 refer to the center ring and the two endplates respectively.

The corresponding (rms) volume and surface power density can be written as

$$\begin{array}{rcl} \frac{dP}{dV} &=& \frac{1}{2} \ \frac{1}{\sigma} \ J^2 \\ \frac{dP}{dA} &=& \delta \ \frac{dP}{dV} = \frac{1}{2} \ \frac{\delta}{\sigma} \ J^2 \end{array}$$

where σ is the conductivity. This yields

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$$\frac{dP_{cr}}{dA} = \frac{1}{2} \frac{B_{\phi}^2(a)}{\mu_0^2 \delta_{cr} \sigma_{cr}} = \frac{1}{2} R_{cr} \left[\frac{E_0}{\mu_0 c} J_1(j_{01}) \right]^2$$

$$\frac{dP_{e1}}{dA} = \frac{1}{2} \frac{B_{\phi}^2(r)}{\mu_0^2 \delta_{e1} \sigma_{e1}} = \frac{1}{2} R_{e1} \left[\frac{E_0}{\mu_0 c} J_1(j_{01} \frac{r}{a}) \right]^2 = \frac{R_{e1}}{R_{cr}} \left[\frac{J_1(j_{01} \frac{r}{a})}{J_1(j_{01})} \right]^2 \frac{dP_{cr}}{dA}$$

$$\frac{dP_{e2}}{dA} = \frac{1}{2} \frac{B_{\phi}^2(r)}{\mu_0^2 \delta_{e2} \sigma_{e2}} = \frac{1}{2} R_{e2} \left[\frac{E_0}{\mu_0 c} J_1(j_{01} \frac{r}{a}) \right]^2 = \frac{R_{e2}}{R_{e1}} \frac{dP_{e1}}{dA}$$

with the surface (sheet) resistance R, skin depth and conductivity related through

$$\delta \simeq \sqrt{\frac{2}{\mu_0 \,\omega \,\sigma}}, \quad R = \frac{1}{\delta \,\sigma} \simeq \sqrt{\frac{\mu_0 \,\omega}{2 \,\sigma}}$$

The total heat deposited on the surface follows from integration of these as

$$P_{cr} = (2\pi a L) \frac{dP_{cr}}{dA} = \pi a L R_{cr} \left[\frac{E_0}{\mu_0 c} J_1(j_{01}) \right]^2$$

$$P_{e1,2} = \frac{R_{e1,2}}{R_{cr}} \frac{a}{2L} P_{cr}$$

$$P = P_{cr} + P_{e1} + P_{e2}$$

Quality factor

Using the expressions for U and P above, the quality factor of the cavity resonator is found as

$$Q = \omega \frac{U}{P} = \frac{\sigma_{cr} R_{cr} a}{1 + \frac{R_{e1} + R_{e2}}{2 R_{cr}} \frac{a}{L}} = \frac{a}{\delta_{cr}} \frac{1}{1 + \frac{\delta_{e1} + \delta_{e2}}{2 \delta_{cr}} \frac{a}{L}}$$

We can express this in terms of the individual components as

$$\frac{1}{Q} = \frac{1}{Q_{cr}} + \frac{1}{Q_{e1}} + \frac{1}{Q_{e2}}$$

where

$$Q_{cr} = \frac{\omega U}{P_{cr}} = \frac{a}{\delta_{cr}}, \quad Q_{e1,2} = \frac{\omega U}{P_{e1,2}} = \frac{2L}{\delta_{e1,2}}$$

Effect of the interface

Consider additional power dissipation P_g and corresponding Q_g at the interfaces (eg. gaskets) between the endplates and the center ring. The resulting Q is

$$\frac{1}{Q} = \frac{1}{Q_{cr}} + \frac{1}{Q_{g1}} + \frac{1}{Q_{e1}} + \frac{1}{Q_{g2}} + \frac{1}{Q_{e2}}$$

Dissipation at the interface is not easy to model. If the endplates and interfaces are the same on both sides, the unknown Q_g can be calculated using the measured cavity Q and the known surface properties.

Effect of coating

A thin layer of TiN is often used as a multipacting barrier. This leads to additional power dissipation on the surface. For a layer of thickness t much less than the skin depth δ_t , the equivalent surface resistance would be

$$R_t = \frac{1}{\sigma_t \, \delta_t} \, \frac{t}{\delta_t}$$

If placed over a substrate with power dissipation P_s , the additional power consumed by the TiN layer can be expressed as

$$\frac{dP_t}{dA} = \frac{R_t}{R_s} \frac{dP_s}{dA}$$

and the effective Q of the surface changes accordingly

$$Q_s \to \left(1 + \frac{R_t}{R_s}\right)^{-1} Q_s$$

Numerical example

Consider the MTA Modular Cavity with

$$a = 14.1 \text{ cm}$$

 $L = 10.3 \text{ cm}$
 $f = 805 \text{ MHz}$

The center ring is made of copper and endplates made of both copper and beryllium are available.

$$\sigma_{Cu} = 6.0 \times 10^7 (\Omega \text{m})^{-1}$$
$$\frac{\sigma_{Be}}{\sigma_{Cu}} = 0.43$$
$$\frac{\sigma_{TiN}}{\sigma_{Be}} = 0.10$$
$$\frac{t}{\delta_t} = 0.01$$

The table below shows various quantities to aid in exploring different endplate configurations. Cavity Q refers to the unloaded quality factor. No correction for the TiN coating is included.

Theory		
Peak energy density		$[4.42 \ (J/m^3)/(MV/m)^2] E_0^2$
Average energy density		$[1.19 (J/m^3)/(MV/m)^2] E_0^2$
Stored energy	U	$[7.65 \text{ mJ}/(\text{MV/m})^2] E_0^2$
Assumed		
Skin depth (Cu)	δ_{Cu}	2.29 μm
Skin depth (Be)	δ_{Be}	$3.49 \ \mu \mathrm{m}$
Surface resistance (Cu)	R_{Cu}	$7.28 \text{ m}\Omega$
Surface resistance (Be)	R_{Be}	$11.1 \text{ m}\Omega$
Surface resistance (TiN)	R_{TiN}	$0.35 \ \mathrm{m} \Omega$
Calculated		
Center ring power	P_{cr}	$[630 \text{ W}/(\text{MV/m})^2] E_0^2$
Endplate power (Cu)	P_e	$[431 \text{ W}/(\text{MV/m})^2] E_0^2$
Endplate power (Be)	P_e	$[658 \text{ W}/(\text{MV/m})^2] E_0^2$
Cavity power (2 Cu ep, no i/f)	Р	$[1.49 \text{ kW}/(\text{MV/m})^2] E_0^2$
Cavity power $(1 \text{ Cu} + 1 \text{ Be ep})$	P	$[1.72 \text{ kW}/(\text{MV/m})^2] E_0^2$
Cavity power (2 Be ep)	P	$[1.95 \text{ kW}/(\text{MV/m})^2] E_0^2$
Component Q (center ring)	Q_{cr}	61.6k
Component Q (Cu endplate)	Q_e	89.8k
Component Q (Be endplate)	Q_e	58.9k
Cavity Q (all Cu, no interface)		26.0k
Cavity Q (1 Cu & 1 Be endplate)		22.5k
Cavity Q (2 Be endplates)		19.9k
Measured		
Measured cavity Q (2 Cu endplates)		21.2k
Measured cavity Q (2 Be endplates)		13.5k
Inferred		
Interface Q (Cu-ep, calculated)	Q_a	231k
Interface Q (Be-ep, calculated)	Q_a	83.8k
Interface power (Cu-ep)	P_a	$[168 \text{ W}/(\text{MV/m})^2] E_0^2$
Interface power (Be-ep)	$P_{g}^{'}$	$[463 \text{ W/(MV/m)^2}] E_0^2$
Predicted		
Expected cavity Q (1 Cu & 1 Be ep)		16.5k
Cavity power (Cu+Cu ep)	P	$[1.83 \text{ kW}/(\text{MV/m})^2] E_0^2$
Cavity power (Be+Cu ep)	P	$[2.35 \text{ kW}/(\text{MV/m})^2] E_0^2$
Cavity power (Be+Be ep)	P	$[2.87 \text{ kW}/(\text{MV/m})^2] E_0^2$